

# Ternary PIN Photodiode with Integrated Preamplifier IC

SRP00264x SRP00265x

#### **Features**

- InGaAs/InP PIN photodiode with preamplifier IC
- Designed for SONET OC-24 applications in fiberoptics communication systems
- Sensitive receiver for 2nd and 3rd optical window (1300 nm and 1550 nm)
- Suitable for bit rates up to 1.25 Gbit/s
- · Module with high optical sensitivity
- Fast switching times
- · Low dark current
- Excellent noise immunity
- High reverse current stability from planar structure
- Hermetically sealed TO46 package







# **Pin Configuration**

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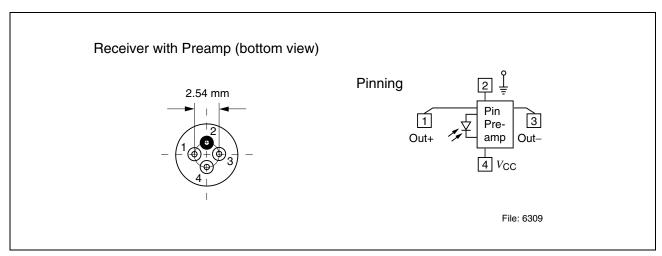


Figure 1 Receiver with Preamp



**Description** 

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The Infineon optical receiver module has been designed for use in optical networks and is suitable for bit rates up to max. 2.5 Gbit/s if used without any TIA.

The optical receiver module uses a high-speed PIN photodetector optional coupled with a hybrid low noise transimpedance amplifier (PIN-TIA). The optical receiver photodiode can be used for 1310 nm or 1550 nm optical communications.

The PIN photodiode is made of InGaAs/InP and has an active diameter of 75  $\mu$ m. The function of the PIN and PIN-TIA optical receiver module is to detect input optical power, to transduce the incident radiation into current (PIN) and then to convert the current into a voltage (PIN-TIA).

The low input noise current density of the used transimpedance amplifiers in PIN-TIA's provides the optical receiver module, when used with appropriate filtering, with ample sensitivity for realizing minimum input power requirements. Designers of optical receivers can use the module in any application that benefits from integration of the photodiode and TIA into a TO coaxial package. Typical for such applications are receivers for digital crossconnects, digital loop carriers, add/drop-multiplexers and optical network units.

Last but not least the fast switching times, low dark currents and the packaging in a compact and hermetically sealed TO46 make the optical receivers usable in many other fiber optic receiver applications. One application is the use in a Compact realization of a transceiver in one module like the so called BIDI® (**Figure 2**).

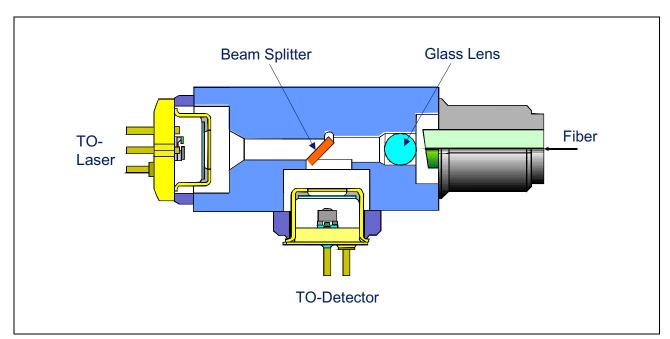


Figure 2 Compact Realization of the Transceiver in One Module



#### **Technical Data**

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#### **Absolute Maximum Ratings**

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Module	-1	-		T.
Operating temperature range at case	$T_{C}$	-40	85	°C
Storage temperature range	$T_{ m stg}$	-40	85	°C
Soldering temperature ( $t_{max} = 10 \text{ s}$ , 2 mm distance from bottom edge of case)	$T_{S}$		260	°C
Receiver Diode				1
Reverse voltage	$V_{R}$		20	V
Forward current	$I_{F}$		10	mA
Optical power into the optical port	$P_{port}$		1	mW

The electro-optical characteristics described in the following table are only valid for use within the specified maximum ratings or under the recommended operating conditions. Characteristics for Pin-Preamp Receivers at  $T_{\rm A} = 25$ °C, unless otherwise specified.

## **Preamp Characteristics**

Parameter	Symbol	Symbol L		Limit Values	
		min.	typ.	max.	
DC-Characteristics		•	•		
Supply voltage	$V_{\sf CC}$	4.5	5	5.5	V
Supply current	$I_{CC}$	35	47	65	mA
AC-Characteristics					
Optical sensitivity (BER ≤ 10 <sup>-9</sup> , PN23)	S	-25	-27		dBm
Linear bandwidth (-3 dB)	BW		800		MHz
Optical overload (avg.)	$P_{max}$		0		dBm
Transimpedance (single ended)	$R_{T}$	20	25	30	kΩ
Output resistance	$R_{\text{out}}$	48	60	72	Ω
Gain (differential)	G		40		V/mW
Return loss, $\lambda = 1310 \text{ nm}$	RL			-27	dB



## **Technical Data**

## **Some Eye Diagrams**

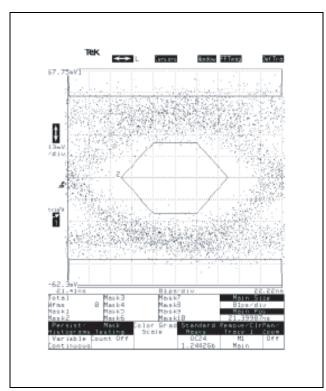
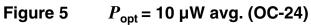
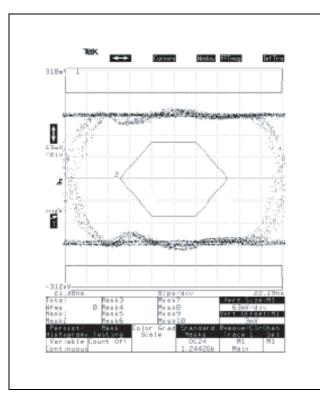


Figure 3  $P_{\text{opt}} = 2 \mu \text{W avg. (OC-24)}$ 





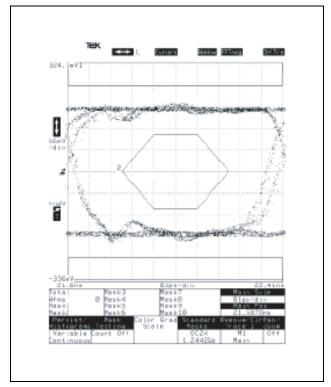


Figure 4  $P_{\text{opt}} = 100 \, \mu\text{W}$  avg. (OC-24) Figure 6

igure 6  $P_{\text{opt}} = 500 \, \mu\text{W} \text{ avg. (OC-24)}$ 

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**Fiber Data** 

## **Fiber Data**

The mechanical fiber characteristics are described in the following table.

## **Fiber Characteristics**

Parameter	Limit Values			Unit
	min.	typ.	max.	
Mode field diameter		50		μm
Cladding diameter	123	125	127	μm
Mode field/cladding concentricity error			1	μm
Cladding non-circularity			2	%
Mode field non-circularity			6	%
Cut off wavelength	1270			nm
Jacket diameter	0.8		1	mm
Bending radius	30			mm
Tensile strength fiber case	5			N
Length	0.8		1.2	m



## **Package Outlines**

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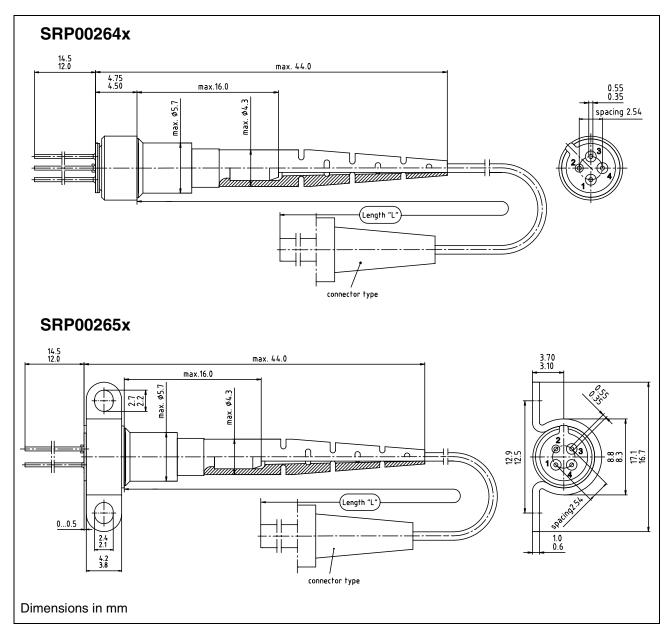


Figure 7



# **Package Outlines**

# **Flange Options**

Туре	Flange
SRP00264x	without
SRP00265x	with

# **Connector Options**

Model	Туре
SRP00264H	MM FC/PC
SRP00265H	
SRP00264G	SM FC/PC
SRP00265G	
SRP00264O	MM SC/PC 0°
SRP00265O	
SRP00264N	SM SC/PC 0°
SRP00265N	
SRP00264Q	MM SC 8° APC
SRP00265Q	
SRP00264P	SM SC 8° APC
SRP00265P	
SRP00264W	MM without connector
SRP00265W	
SRP00264Z	SM without connector
SRP00265Z	

Other connectors on request.

#### SRP00264x SRP00265x

Revision History:	2003-04-28	DS1
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Previous Version: 2001-12-01

Page	Subjects (major changes since last revision)
2	Figure 1 changed

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